



# <u>MMDT5551</u>

### DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

# Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMDT5401)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

# Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4N, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



	SOT-363									
Dim	Min	Max								
Α	0.10	0.30								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 Nominal									
F	0.30	0.40								
н	1.80	2.20								
J	—	0.10								
κ	0.90	1.00								
L	1.80 2.20   — 0.10   0.90 1.00   0.25 0.40									
м	0.10	0.25								
α	0°	8°								
All Dir	nensions	in mm								

# Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Collector-Base Voltage		V <sub>CBO</sub>	180	V		
Collector-Emitter Voltage		V <sub>CEO</sub>	160	V		
Emitter-Base Voltage		V <sub>EBO</sub>	6.0	V		
Collector Current - Continuous	(Note 1)	Ι <sub>C</sub>	200	mA		
Power Dissipation	(Note 1, 2)	Pd	200	mW		
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ ext{ heta}JA}$	625	°C/W		
Operating and Storage Temperature Range		Тj, T <sub>STG</sub>	-55 to +150	°C		

1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Maximum combined dissipation.

3. No purposefully added lead.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

Notes:



#### Electrical Characteristics $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)			•	•	·
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	180	_	V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	160		V	I <sub>C</sub> = 1.0mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0	_	V	$I_{\rm E} = 10 \mu A, I_{\rm C} = 0$
Collector Cutoff Current	I <sub>CBO</sub>		50	nA μA	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0 V <sub>CB</sub> = 120V, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C
Emitter Cutoff Current	I <sub>EBO</sub>	_	50	nA	V <sub>EB</sub> = 4.0V, I <sub>C</sub> = 0
ON CHARACTERISTICS (Note 6)					
DC Current Gain	h <sub>FE</sub>	80 80 30	250 —	_	$    I_{C} = 1.0 mA, V_{CE} = 5.0 V \\     I_{C} = 10 mA, V_{CE} = 5.0 V \\     I_{C} = 50 mA, V_{CE} = 5.0 V $
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.15 0.20	V	$I_{C}$ = 10mA, $I_{B}$ = 1.0mA $I_{C}$ = 50mA, $I_{B}$ = 5.0mA
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	1.0	V	$I_{C}$ = 10mA, $I_{B}$ = 1.0mA $I_{C}$ = 50mA, $I_{B}$ = 5.0mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C <sub>obo</sub>	_	6.0	pF	V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0
Small Signal Current Gain	h <sub>fe</sub>	50	250	—	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1.0mA, f = 1.0kHz
Current Gain-Bandwidth Product	f <sub>T</sub>	100	300	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA, f = 100MHz
Noise Figure	NF	_	8.0	dB	$V_{CE}$ = 5.0V, I <sub>C</sub> = 200µA, R <sub>S</sub> = 1.0kΩ, f = 1.0kHz

Notes:

6. Short duration pulse test used to minimize self-heating effect.











# Ordering Information (Note 7)

Device	Packaging	Shipping
MMDT5551-7-F	SOT-363	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



K4N = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	К	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z
											-				
				-	-		- I -			-	-	-			_

Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



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